

Low Phase Noise VCXO with multipliers (for 100-200MHz Fund Xtal)

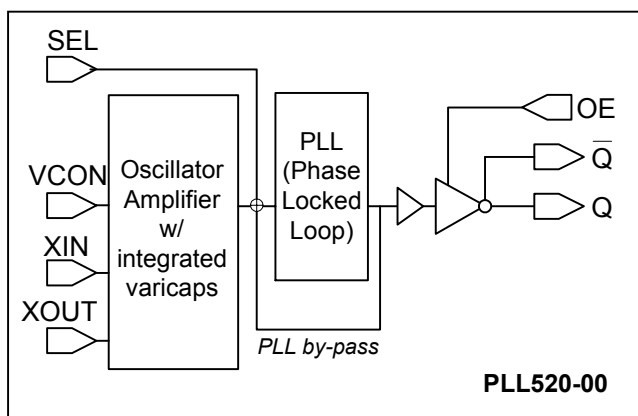
FEATURES

- 100MHz to 200MHz Fundamental Mode Crystal.
- Output range: 100 – 200MHz (no multiplication), 200 – 400MHz (2x multiplier), 400 – 700MHz (4x multiplier), or 800MHz – 1GHz (LVDS output only for 8x multiplier).
- Available outputs: PECL, LVDS, or CMOS (High Drive (30mA) or Standard Drive (10mA) output).
- Selectable OE Logic (enable high or enable low).
- Integrated variable capacitors.
- Supports 3.3V-Power Supply.
- Available in die form.
- Thickness 10 mil.

DESCRIPTION

PLL520-00 is a VCXO IC specifically designed to pull high frequency fundamental crystals. Its design was optimized to tolerate higher limits of interelectrodes capacitance and bonding capacitance to improve yield. It achieves very low current into the crystal resulting in better overall stability. Its internal varicaps allow an on chip frequency pulling, controlled by the VCON input.

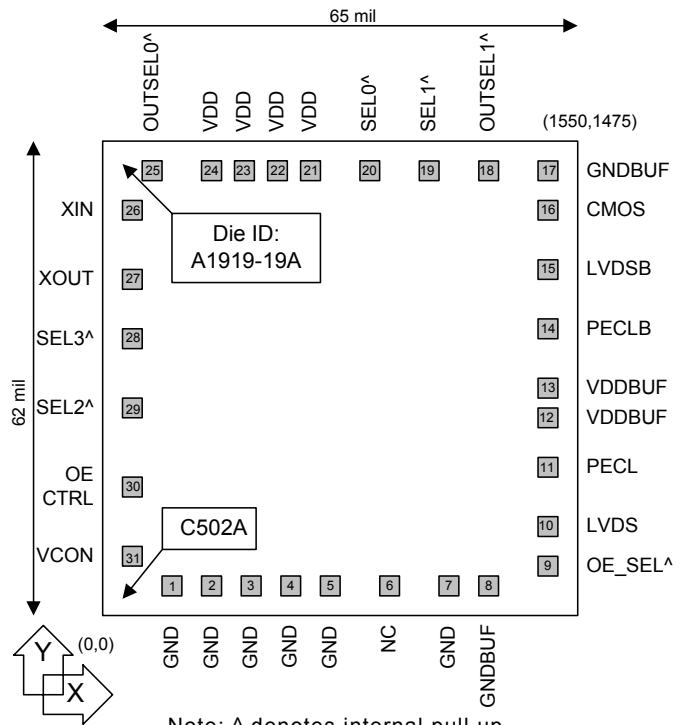
BLOCK DIAGRAM



DIE SPECIFICATIONS

Name	Value
Size	65 x 62 mil
Reverse side	GND
Pad dimensions	80 micron x 80 micron
Thickness	10 mil

DIE CONFIGURATION



OUTPUT SELECTION AND ENABLE

OUTSEL1 (Pad #18)	OUTSEL0 (Pad #25)	Selected Output
0	0	High Drive CMOS
0	1	Standard CMOS
1	0	LVDS
1	1	PECL (default)

OE_SELECT (Pad #9)	OE_CTRL (Pad #30)	State
0	0	Tri-state
	1 (Default)	Output enabled
1 (Default)	0 (Default)	Output enabled
	1	Tri-state

Pad #9, 18, 25: Bond to GND to set to "0". No connection results to "default" setting through internal pull-up.

Pad #30: Logical states defined by PECL levels if OE_SELECT (pad #9) is "1"
Logical states defined by CMOS levels if OE_SELECT is "0"

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FREQUENCY SELECTION TABLE

Pad #28 SEL3	Pad #29 SEL2	Pad #19 SEL1	Pad #20 SELO	Selected Multiplier
0	0	1	1	Fin x 8 (LVDS outputs only)
1	0	1	1	Fin x 4
1	1	1	0	Fin x 2
1	1	1	1	No multiplication (no PLL)

All pads have internal pull-ups (default value is 1). Bond to GND to set to 0.

ELECTRICAL SPECIFICATIONS
1. Absolute Maximum Ratings

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	V_{DD}		4.6	V
Input Voltage, dc	V_I	-0.5	$V_{DD}+0.5$	V
Output Voltage, dc	V_O	-0.5	$V_{DD}+0.5$	V
Storage Temperature	T_S	-65	150	°C
Ambient Operating Temperature*	T_A	-40	85	°C
Junction Temperature	T_J		125	°C
Lead Temperature (soldering, 10s)			260	°C
ESD Protection, Human Body Model			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

* Note: Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for COMMERCIAL grade only.

2. Crystal Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Crystal Resonator Frequency	F_{XIN}	Parallel Fundamental Mode	100		200	MHz
Crystal Loading Rating	C_L (xtal)	Die at VCON = 1.65V		4		pF
Interelectrode Capacitance	C_0				3.5	pF
Crystal Pullability	C_0/C_1 (xtal)	AT cut			250	-
Recommended ESR	R_E	AT cut			30	Ω

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3. Voltage Control Crystal Oscillator

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
VCXO Stabilization Time *	T _{VCXOSTB}	From power valid			10	ms
VCXO Tuning Range		F _{XIN} = 100 – 200MHz; XTAL C ₀ /C ₁ < 250 0V ≤ VCON ≤ 3.3V		200*		ppm
CLK output pullability		VCON=1.65V, ±1.65V	±100*			ppm
On-chip Varicaps control range		VCON = 0 to 3.3V		4 – 18*		pF
Linearity					10*	%
VCXO Tuning Characteristic				65		ppm/V
VCON input impedance				60		kΩ
VCON modulation BW		0V ≤ VCON ≤ 3.3V, -3dB	25			kHz

Note: Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits.

4. General Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current (Loaded Outputs)	I _{DD}	PECL/LVDS/CMOS			100/80/40	mA
Operating Voltage	V _{DD}		2.97		3.63	V
Output Clock Duty Cycle		@ 50% V _{DD} (CMOS) @ 1.25V (LVDS) @ V _{DD} – 1.3V (PECL)	45	50	55	%
Short Circuit Current				±50		mA

5. Jitter Specifications

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period jitter RMS	At 155.52MHz, with capacitive decoupling between VDD and GND. Over 10,000 cycles		2.5		ps
Period jitter peak-to-peak			18.5	20	
Accumulated jitter RMS	At 155.52MHz, with capacitive decoupling between VDD and GND. Over 1,000,000 cycles.		2.5		ps
Accumulated jitter peak-to-peak			24	27	
Random Jitter	“RJ” measured on Wavecrest SIA 3000		2.5		ps
Integrated jitter RMS at 155MHz	Integrated 12 kHz to 20 MHz		0.3	0.4	ps
Period jitter RMS	At 622.08MHz, with capacitive decoupling between VDD and GND. Over 10,000 cycles		11		ps
Period jitter peak-to-peak			45	49	
Accumulated jitter RMS	At 622.08MHz, with capacitive decoupling between VDD and GND. Over 1,000,000 cycles.		11		ps
Accumulated jitter peak-to-peak			24	27	
Random Jitter	“RJ” measured on Wavecrest SIA 3000		3		ps
Integrated jitter RMS at 622MHz	Integrated 12 kHz to 20 MHz		1.6	1.8	ps

Measured on Wavecrest SIA 3000

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6. Phase Noise Specifications

PARAMETERS	FREQUENCY	@10Hz	@100Hz	@1kHz	@10kHz	@100kHz	UNITS
Phase Noise relative to carrier	155.52MHz	-75	-95	-125	-140	-145	dBc/Hz
	622.08MHz	-75	-95	-110	-125	-120	

Note: Phase Noise measured at VCON = 0V

7. CMOS Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output drive current (High Drive)	I _{OH}	V _{OH} = V _{DD} -0.4V, V _{DD} =3.3V	30			mA
	I _{OL}	V _{OL} = 0.4V, V _{DD} = 3.3V	30			mA
Output drive current (Standard Drive)	I _{OH}	V _{OH} = V _{DD} -0.4V, V _{DD} =3.3V	10			mA
	I _{OL}	V _{OL} = 0.4V, V _{DD} = 3.3V	10			mA
Output Clock Rise/Fall Time (Standard Drive)		0.3V ~ 3.0V with 15 pF load		2.4		ns
Output Clock Rise/Fall Time (High Drive)		0.3V ~ 3.0V with 15 pF load		1.2		

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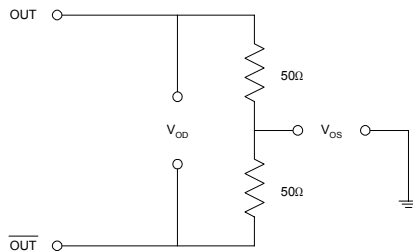
8. LVDS Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	V_{OD}	$R_L = 100 \Omega$ (see figure)	247	355	454	mV
V_{DD} Magnitude Change	ΔV_{OD}		-50		50	mV
Output High Voltage	V_{OH}			1.4	1.6	V
Output Low Voltage	V_{OL}		0.9	1.1		V
Offset Voltage	V_{OS}		1.125	1.2	1.375	V
Offset Magnitude Change	ΔV_{OS}		0	3	25	mV
Power-off Leakage	I_{OXD}	$V_{out} = V_{DD}$ or GND $V_{DD} = 0V$		± 1	± 10	μA
Output Short Circuit Current	I_{OSD}			-5.7	-8	mA

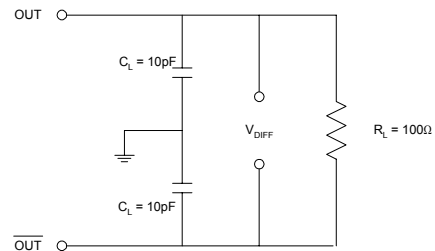
9. LVDS Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	t_r	$R_L = 100 \Omega$ $C_L = 10 \text{ pF}$ (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	t_f		0.2	0.7	1.0	ns

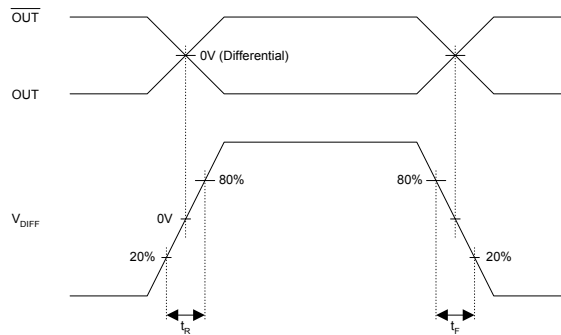
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transition Time Waveform



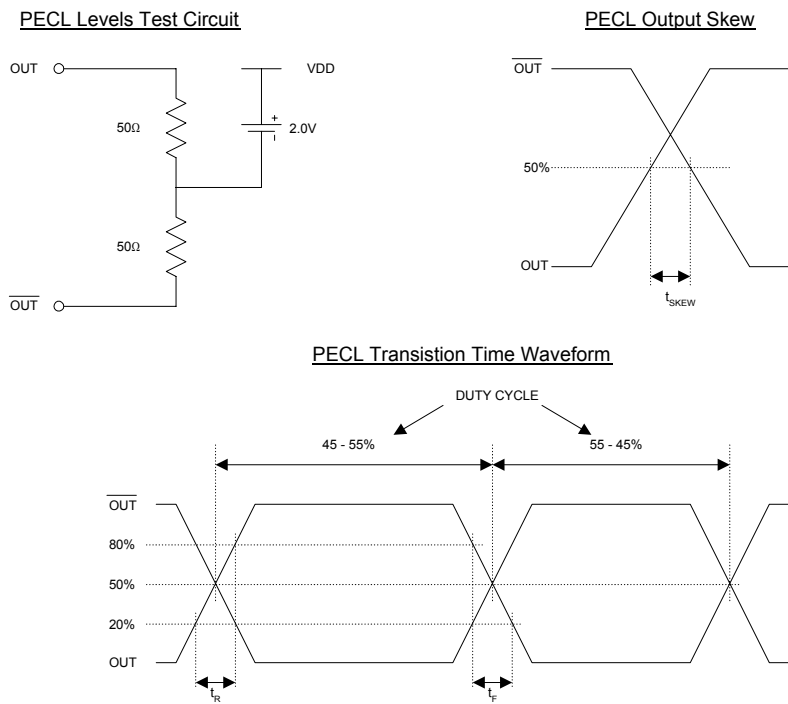
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10. PECL Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Output High Voltage	V_{OH}	$R_L = 50 \Omega$ to $(V_{DD} - 2V)$ (see figure)	$V_{DD} - 1.025$		V
Output Low Voltage	V_{OL}			$V_{DD} - 1.620$	V

11. PECL Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	t_r	@20/80% - PECL		0.6	1.5	ns
Clock Fall Time	t_f	@80/20% - PECL		0.5	1.5	ns



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PAD ASSIGNMENT

Pad #	Name	X (μm)	Y (μm)	Description
1	GND	248	109	Ground.
2	GND	361	109	Ground.
3	GND	473	109	Ground.
4	GND	587	109	Ground.
5	GND	702	109	Ground.
6	N/C	874	109	No Connection.
7	GND	1042	109	Ground.
8	GNDBUF	1171	109	Ground, Buffer circuitry.
9	OE_SELECT	1400	125	Used to select between PECL or CMOS logic states for OE. See Output Selection and Enable table on page 1. Internal pull up.
10	LVDS	1400	259	LVDS output.
11	PECL	1400	476	PECL output.
12	VDDBUF	1400	616	3.3V power supply, Buffer circuitry.
13	VDDBUF	1400	716	3.3V power supply, Buffer circuitry.
14	PECLB	1400	871	Complementary PECL output.
15	LVDSB	1400	1089	Complementary LVDS output.
16	CMOS	1400	1227	CMOS output
17	GNDBUF	1389	1365	Ground, Buffer Circuitry.
18	OUTSEL1	1232	1365	Used to select CMOS, PECL or LVDS output type. See Output Selection and Enable table on page 1. Internal pull up.
19	SEL1	1042	1365	Used to select multiplication factor. See Frequency Selection table on page 1. Internal pull up.
20	SEL0	854	1365	Used to select multiplication factor. See Frequency Selection table on page 1. Internal pull up.
21	VDD	659	1365	3.3V power supply.
22	VDD	559	1365	3.3V power supply.
23	VDD	459	1365	3.3V power supply.
24	VDD	358	1365	3.3V power supply.
25	OUTSEL0	194	1365	Used to select CMOS, PECL or LVDS output type. See Output Selection and Enable table on page 1. Internal pull up.
26	XIN	109	1223	Crystal input. See crystal specification page 2.
27	XOUT	109	1017	Crystal output. See crystal specification page 2.
28	SEL3	109	858	Used to select multiplication factor. See Frequency Selection table on page 1. Internal pull up.
29	SEL2	109	646	Used to select multiplication factor. See Frequency Selection table on page 1. Internal pull up.
30	OE_CTRL	109	397	Used to enable/disable the output(s). See Output Selection and Enable table on page 1.
31	VCON	109	181	Voltage Control input. 0V to 3.3V.

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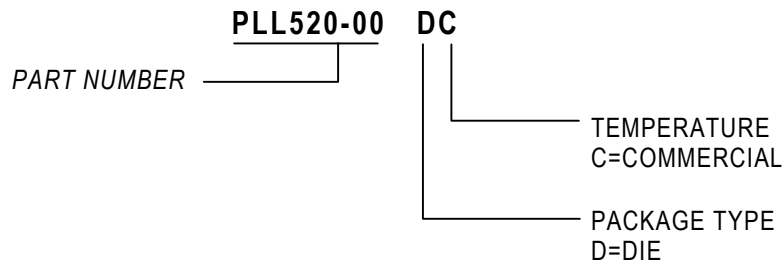
ORDERING INFORMATION

For part ordering, please contact our Sales Department:

47745 Fremont Blvd., Fremont, CA 94538, USA
Tel: (510) 492-0990 Fax: (510) 492-0991

PART NUMBER

The order number for this device is a combination of the following:
Device number, Package type and Operating temperature range



<u>Order Number</u>	<u>Marking</u>	<u>Package Option</u>
PLL520-00DC	P520-00DC	Die – Waffle Pack

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